

ISC Silicon NPN Power Transistor

2SD956

DESCRIPTION

- · High Breakdown Voltage-
 - : V_{CBO}= 1500V (Min)
- · Low Collector Saturation Voltage-
 - : V_{CE(sat)}= 4.0V(Max.)@ I_C= 2A
- · Built-in Damper Diode
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

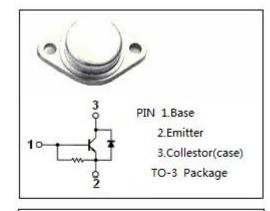


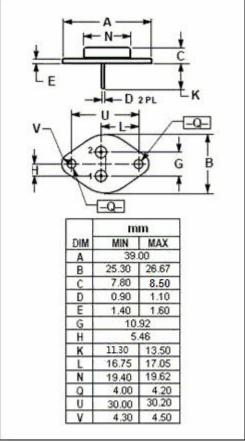
APPLICATIONS

• Designed for line-operated horizontal deflection output applications.



SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	1500	V	
Vces	Collector-Emitter Voltage	1500	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current- Continuous	2.5	А	
Іср	Collector Current- Peak	4.5	Α	
Pc	Collector Power Dissipation @ T _C = 25 °C	50	W	
TJ	unction Temperature 150		$^{\circ}$	
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{EBO}	Emitter-Base Breakdown Voltage	I _E = 200mA; I _C = 0	5.0			V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.75A			4.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I _C = 2A; I _B = 0.75A			1.5	V
Ісво	Collector Cutoff Current	V _{CB} = 750V; I _E = 0			50	μ А
		V _{CB} = 1500V; I _E = 0			0.5	mA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 5V	8		36	
V _{ECF}	C-E Diode Forward Voltage	I _F = 3A			1.7	V
t _{stg}	Storage Time	I _C = 2A, I _{Bend} = 0.75A; L _B = 10 µ Н			10	μS
t _f	Fall Time	IC- ZA, IBend- U./ JA, LB- IU μ Π			1.0	μ \$

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